

P-Channel Enhancement Mode MOSFET

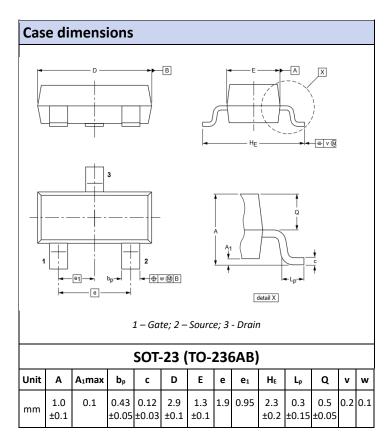
Primary characteristics			
Symbol	Parameter	Value	Unit
I _D	Continuous drain current (@Ta=25°C)	4.2	А
V _{DS}	Drain source voltage	30	V

Features

- SOT-23 case for easy automatic insertion
- Pb-free and RoHS compliant

Application

- Battery protection
- Load switch
- Uninterruptable power supply



Absolute maximum ratings (T _A = 25°C unless otherwise noted)					
Characteristic		Symbol	Value	Unit	
Drain-source voltage		V _{DS}	30	V	
Gate-source voltage		V _{GS}	±12	V	
Continuous drain current	V _{GS} =10V, T _C =25°C ¹⁾		4.2		
	V _{GS} =10V, T _C =100°C ¹⁾	I _D	2.7	A	
Pulsed drain current 1)	•	I _{DM}	16.8	Α	
Power Dissipation		P _D	1.5	W	
Thermal resistance junction-ambient	1)	R _{eJA}	125	°C/W	
Thermal resistance junction-case 1)		R _{eJC}	124	°C/W	
Operating junction temperature rang	ge	T _J , T _{STG}	-55 ~ 150	°C	



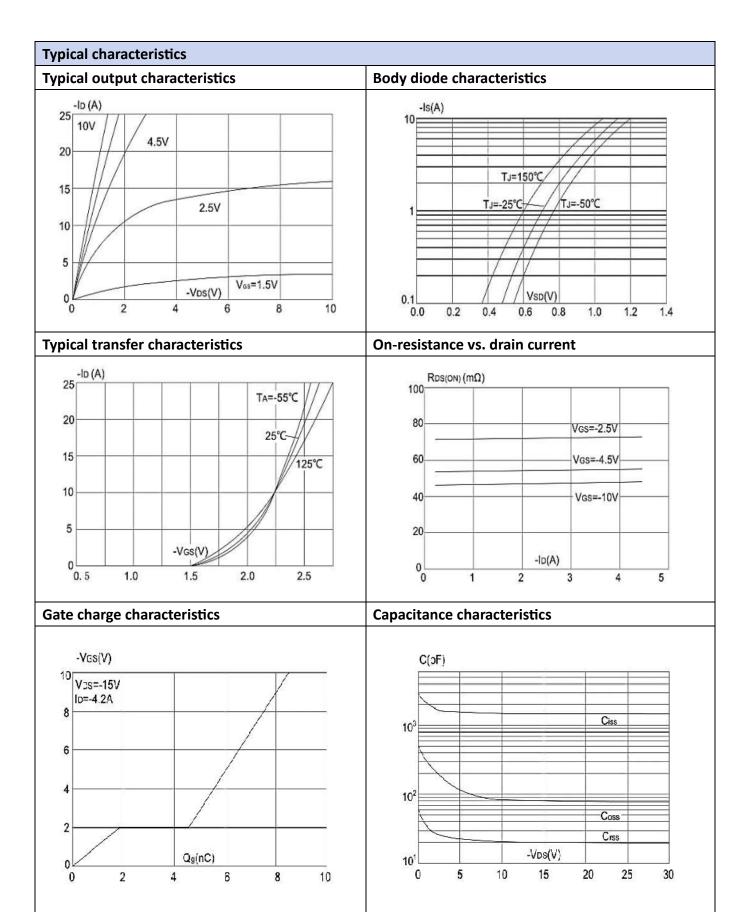
Electrical characteristics (T _A = 25°C)							
Characteristic	Test condition	Symbol	Min.	Value Typ.	Max.	Unit	
Drain-source breakdown voltage	V _{GS} =0V, I _D =250μA	V _{(BR)DSS}	-30	-	-	V	
Zero gate voltage drain current	V _{DS} =30V, V _{GS} =0V	I _{DSS}	-	-	1.0	μΑ	
Gate to body leakage current	V _{GS} =±12V, V _{DS} =0V	I _{GSS}	-	-	±100	nA	
Gate threshold voltage	V _{DS} =V _{GS} , I _D =250ųA	V _{GS(TH)}	0.5	0.9	1.5	V	
	V _{GS} =10V, I _D =4.0A		-	45	55		
Static drain-source on-state resistance 3)	V _{GS} =4.5V, I _D =3.0A	R _{DS(ON)}	-	53	68	mΩ	
	V _{GS} =2.5V, I _D =1.0A		-	72	96		
Dynamic electrical characteristics							
Characteristic	Test condition	Symbol	D.d.i.e	Value		Unit	
Innut conscitones		-	Min.	Typ.	Max.		
Input capacitance	V_{DS} =15V V_{GS} =0V	Ciss	-	1500	-	nΓ	
Output capacitance Reverse transfer capacitance	f=1.0MHz	Coss	-	80	_	pF	
•	V _{DS} =15V	Crss	-	2.0 8.5	-		
Total gate charge Gate source charge	V _{DS} =13V V _{GS} =10V	Qg	-	1.8	_	nC	
Gate drain ("Miller") charge	I _D =4.2A	Q _{gs}	_	2.7		iic	
		Qga		2.7			
Switching characteristics			1	Value			
Characteristic	Test condition	Symbol	Value Min. Typ. Max.		Unit		
Turn on dolay time		+	IVIIII.	7.0	iviax.	no	
Turn on delay time Turn on rise time	V _{DS} =15V	t _{d(on)}	-	3.0	-	ns	
	V _{GS} =10V I _D =1.0A		-	20	-	ns	
Turn off delay time Turn off fall time	R _G =2.5Ω	t _{d(off)}	-	12	-	ns	
		t _f	-	12	_	ns	
Source drain diode characteristics			<u> </u>				
Characteristic	Test condition	Symbol	Min.	Value Typ.	Max.	Unit	
Maximum continuous drain to source diode forward current	-	Is	-	-	4.2	A	
Maximum pulsed drain to source diode forward current	-	I _{SM}	-	-	16.8	A	
Drain-source diode forward voltage	I _S =4.2A, V _{GS} =0V	V _{SD}	-	0.8	1.2	V	

Notes:

- 1) The data tested while surface mounted on a 1 inch FR-4 board with 2oz copper
- 2) The data tested with a pulse, pulse width ≤300µs, duty cycle ≤2%
- 3) The power dissipation is limited by 150°C junction temperature
- 4) The data is theoretically the same as I_D and I_{DM}, in real applications should be limited by total power dissipation

Akyga semi Page 2/5 2023-09; REV. 1

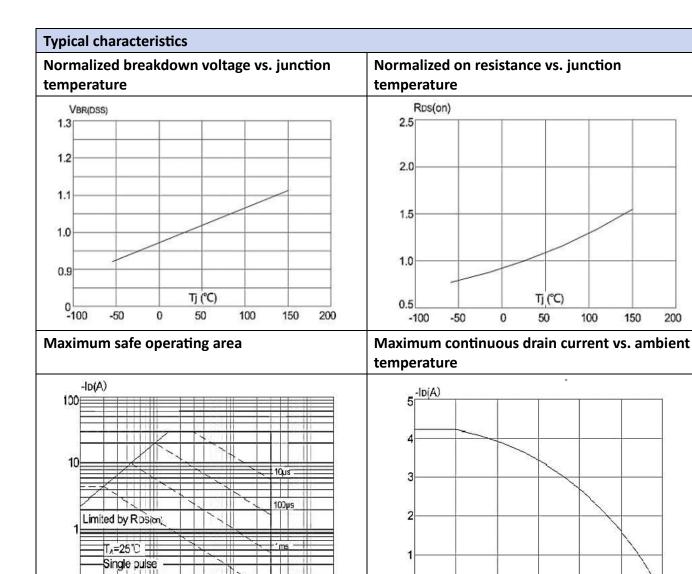






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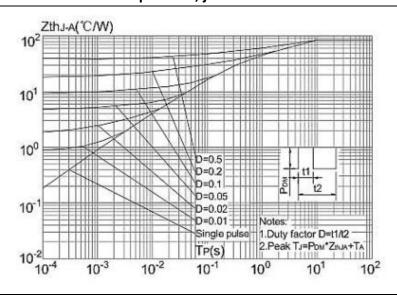
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Maximum effective transient thermal impedance, junction-to-ambient

DC

100



0

25

TA (°C)

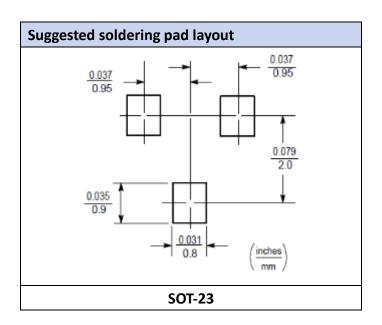
100

125

150



Ordering information			
Part Number	Package	Shipping Quantity	Dimensions
AKS3401B	SOT-23	3000 pcs / reel	



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Akyga semi Page 5/5 2023-09; REV. 1